TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOS V)

## **TPC8117**

### Lithium Ion Battery Applications Notebook PC Applications

• Small footprint due to small and thin package

• Low drain-source ON-resistance :  $R_{DS}(ON) = 3.0 \text{ m}\Omega \text{ (typ.)}$ 

• High forward transfer admittance  $|Y_{fs}| = 54 \text{ S (typ.)}$ 

• Low leakage current:  $IDSS = -10 \mu A (max) (VDS = -30 V)$ 

• Enhancement mode:  $V_{th} = -0.8 \text{ to } -2.0 \text{ V (V}_{DS} = -10 \text{ V}, I_D = -1 \text{ mA})$ 

#### Absolute Maximum Ratings (Ta = 25°C)

Characteri	stics	Symbol	Rating	Unit
Drain-source voltage		$V_{DSS}$	-30	V
Drain-gate voltage (Ro	$_{\rm SS} = 20 \text{ k}\Omega$ )	$V_{DGR}$	-30	V
Gate-source voltage		V <sub>GSS</sub>	±20	V
Drain current	DC (Note 1)	ΙD	-18	Α
	Pulse (Note 1)	I <sub>DP</sub>	-72	A
Drain power dissipatio	n (t = 10 s) (Note 2a)	PD	1.9	⟨w
Drain power dissipatio	n (t = 10 s) (Note 2b)	PD	1.0	w
Single pulse avalanche	e energy (Note 3)	EAS	211	/mJ
Avalanche current	(	IAR	-18	A
Repetitive avalanche e	energy lote 2a) (Note 4)	EAR	0.030	mJ
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature r	ange	T <sub>stg</sub>	-55 to 150	°C

Note 1, Note 2, Note 3 and Note 4: See the next page.

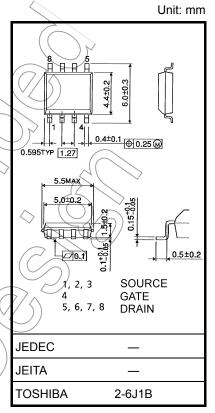
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating)

temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions")"Derating

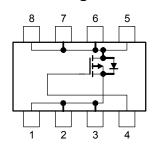
Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.080 g (typ.)

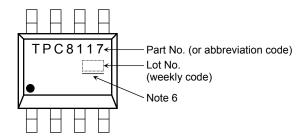
#### **Circuit Configuration**



#### **Thermal Characteristics**

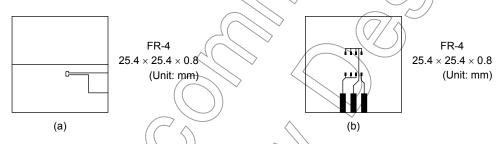
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R <sub>th (ch-a)</sub>	65.8	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R <sub>th (ch-a)</sub>	125	°C/W

#### Marking (Note 5)



Note 1: Ensure that the channel temperature does not exceed 150°C

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



Note 3:  $V_{DD} = -24 \text{ V}$ ,  $T_{ch} = 25^{\circ}\text{C}$  (initial),  $L = 500 \mu\text{H}$ ,  $R_G = 25 \Omega$ ,  $L_{RR} = -18 \text{ A}$ 

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: • on the lower left of the marking indicates Pin 1.

\* Weekly code: (Three digits)

Week of manufacture
(01 for first week of year, continuing up to 52 or 53)

Year of manufacture

(The last digit of the calendar year)

Note 6: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

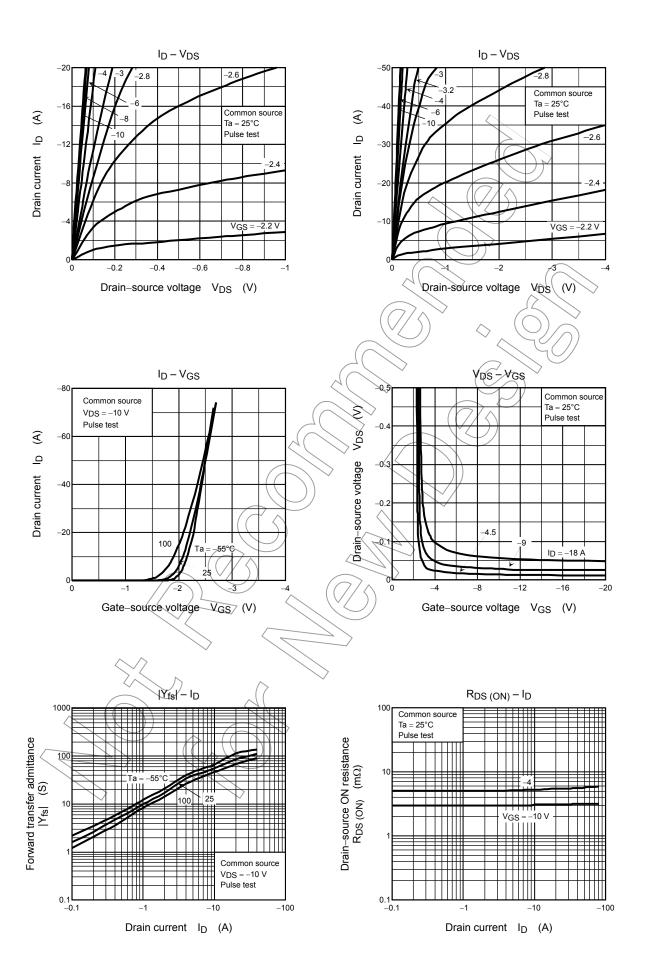
2 2009-09-29

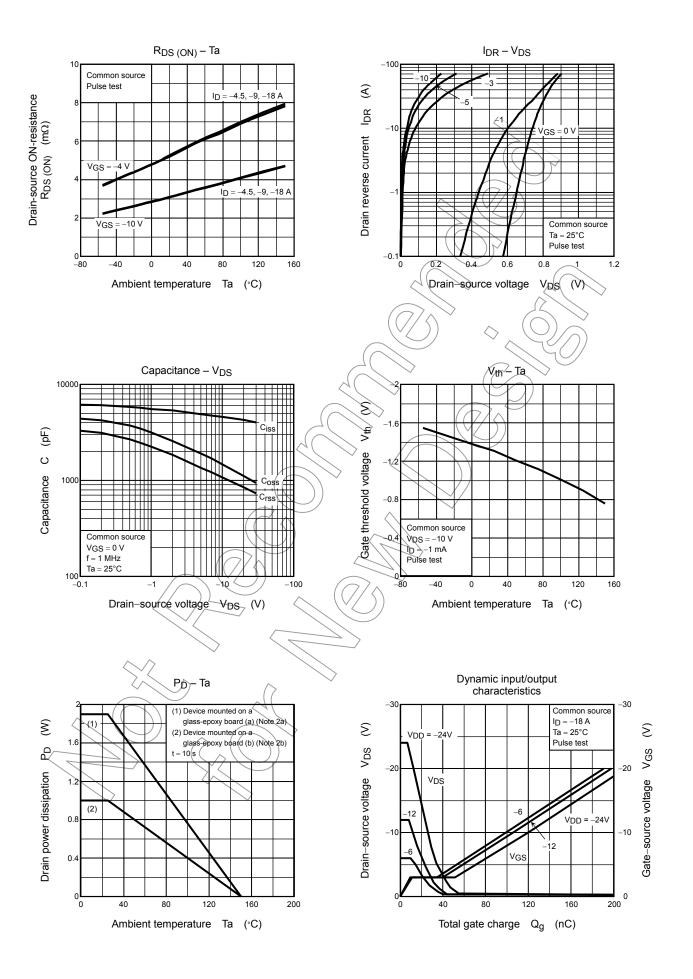
## Electrical Characteristics (Ta = 25°C)

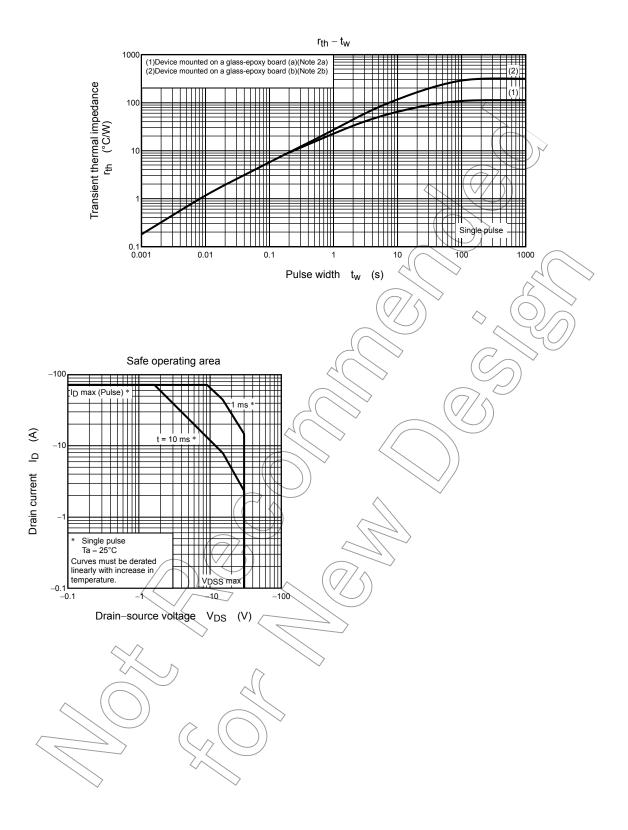
Char	racteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage curre	ent	I <sub>GSS</sub>	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±100	nA
Drain cut-OFF curi	rent	I <sub>DSS</sub>	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$	_	_	-10	μА
Drain-source breakdown voltage		V (BR) DSS	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-30	_	_	V
		V <sub>(BR)DSX</sub>	$I_D = -10 \text{ mA}, V_{GS} = 20 \text{ V}$	13	_	_	
Gate threshold vol	tage	V <sub>th</sub>	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$	0.8	) >	-2.0	٧
Drain-source ON-resistance		D (2)	$V_{GS} = -4 \text{ V}, I_D = -9 \text{ A}$	) /\	5.5	7.9	- mΩ
		R <sub>DS</sub> (ON)	$V_{GS} = -10 \text{ V}, I_D = -9 \text{ A}$	$\rightarrow$	3.0	3.9	
Forward transfer a	dmittance	Y <sub>fs</sub>	$V_{DS} = -10 \text{ V}, I_D = -9 \text{ A}$	27	54	_	S
Input capacitance		C <sub>iss</sub>		_	4600	_	
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	970	_	pF
Output capacitance		Coss			1500	$\nearrow$	
Switching time	Rise time	t <sub>r</sub>	V <sub>GS</sub> -10 V   D = -9 A   C   C   C   C   C   C   C   C   C	-	10	> _	- ns
	Turn-ON time	t <sub>on</sub>			20	_	
	Fall time	t <sub>f</sub>			300	_	
	Turn-OFF time	t <sub>off</sub>	V <sub>DD</sub> ≈ 15 V Duty ≤ 1%, t <sub>w</sub> = 10 μs	) —	800	_	
Total gate charge (gate-source plus	gate-drain)	Qg	V <sub>DD</sub> ≈ -24 V, V <sub>GS</sub> = -10 V,	_	130	_	
Gate-source charge 1		$Q_{gs1}$	I <sub>D</sub> = -18 A	_	12	_	nC
Gate-drain ("miller") charge		Qgd		_	40	_	

# Source-Drain Ratings and Characteristics (Ta = 25°C)

Charac	eteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current	Pulse (Note 1)	I <sub>DRP</sub>	_	_	_	-72	А
Forward voltage (diod	de)	VDSF	$I_{DR} = -18 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	1.2	V







6 2009-09-29

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